

4-TO-2 DVI/HDMI SWITCH

FEATURES

- A 4-to-2 Single-Link or 2-to-1 Dual-Link DVI/HDMI Physical Layer Switch
- Compatible with HDMI 1.3a
- Supports 2.25 Gbps Signaling Rate for 480i/p, 720i/p, and 1080i/p Resolutions up to 12-Bit Color Depth
- Integrated Receiver Terminations
- 8-dB Receiver Equalizer Compensates for Losses From Standard HDMI Cables
- Selectable Output De-Emphasis Compensates for Losses From Flat Cables
- High-Impedance Outputs When Disabled

 I²C Repeater Isolates Bus Capacitance at Both Ends

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- TMDS Inputs HBM ESD Protection Exceeds 6 kV
- 3.3-V Supply Operation
- 128-Pin TQFP Package
- ROHS Compatible and 260°C Reflow Rated

APPLICATIONS

- Digital TV
- Digital Projector
- Audio Video Receiver
- DVI or HDMI Switch

DESCRIPTION

The TMDS442, 4-to-2 port DVI/HDMI switch, allows up to 4 digital video interface (DVI) or high-definition multimedia interface (HDMI) ports to be switched to two independent display blocks. The essential requirement of picture-in-picture display from two digital audiovisual sources is having two individual DVI or HDMI receivers in a digital display system. TMDS442 supports two DVI or HDMI receivers to enable multiple-source selection (picture-in-picture), as well as supports acting as a 4-input 1-output video switch.

Each input or output port contains one 5-V power indicator (5V_PWR), one hot plug detector (HPD), a pair of I²C interface signals (SCL/SDA), and four TMDS channels supporting data rates up to 2.25 Gbps. The 5-V power indicator and the hot plug detector are pulled down with internal resistors, forcing a low state on these pins until receiving a valid high signal. The I²C interface is constructed by an I²C repeater circuit to isolate the capacitance form both ends of the buses. TMDS receivers integrate 50- Ω termination resistors pulled up to V_{CC}, which eliminates the need for external terminations. An 8-dB input equalization cooperates to each TMDS receiver inputs to optimize system performance through 5-meter or longer DVI or HDMI compliant cables.



TYPICAL APPLICATION

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A precision resistor is connected externally from the VSADJ pin to ground, for setting the differential output voltage to be compliant with the TMDS standard for all TMDS driver outputs. The PRE pin controls the TMDS output to be operated under either a standard TMDS mode or an AC de-emphasis mode. When PRE = high, a 3-dB AC de-emphasis TMDS output swing is selected to pre-condition the output signals to overcome signal impairments that may exist between the output of the TMDS442 and the HDMI receiver placed at a remote location.

Each sink output port can be configured with the SA, SB, \overline{OE} , I2CEN, and PRE pins. SA1, SB1, $\overline{OE1}$, I2CEN1, and PRE1 regulate the behaviour of sink port 1; SA2, SB2, $\overline{OE2}$, I2CEN2, and PRE2 regulate the behaviour of sink port 2. These control signals are hard-wire controlled by GPIO interface, or through a local I²C interface. When GE = low, the configurations are done through a local I²C interface, LC_SCL, LC_SDA, LC_A0, and LC_A1 pins, and the 5V_EN can be programmed through the local I²C interface. It is default high after device powered on. When GE = high, the configurations are done through GPIO pins regardless the value of the 5V_EN in the internal I²C registers.

The two bit source selector pins, SA and SB, determine the source transferred to the sink port. The internal multiplexer interconnects the TMDS channels and I²C interface from the selected source port to the sink port. The HPD output of the selected source port follows the status of the HPD_SINK. Since two of the source ports will always be unconnected to any output, the I²C interfaces of unselected ports are isolated and the HPD outputs of an unselected port are pulled low.

The TMDS outputs of each of the sink ports are enabled based on the \overline{OE} signal and 5V_PWR signal (from the selected source port). When \overline{OE} is low, for an output port, and the 5V_PWR signal from the selected source port is high, the TMDS output signals are enabled; otherwise they are disabled, and high impedance.

The I²C driver at sink side, SCL_SINK and SDA_SINK, are enabled by setting I2CEN high. When I2CEN is low, the I²C driver can not forward a low state to the I²C bus connected at the sink port. A hard wire output voltage select pin, OVS, allows adjustable output voltage level to SCL_SINK and SDA_SINK to optimise noise margins while interfacing to different HDMI receivers. The I²C driver of each source port, SCL and SDA, is controlled by its 5V_PWR signal. A valid 5-V signal appearing at the input of 5V_PWR enables the I²C driver of the source port.

The device is packaged in a 128-pin PowerPAD TQFP package and characterized for operation from 0°C to 70°C.

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.



FUNCTIONAL BLOCK DIAGRAM

TMDS442

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TERMINAL FUNCTIONS

TERMINAL		1/0	DESCRIPTION		
NAME	NO.	I/O	DESCRIPTION		
A11, A12, A13, A14 A21, A22, A23, A24 A31, A32, A33, A34 A41, A42, A43, A44	8, 11, 14, 17 118, 121, 124, 127 100, 103, 106, 109 82, 85, 88, 91	I	Source port 1 TMDS positive inputs Source port 2 TMDS positive inputs Source port 3 TMDS positive inputs Source port 4 TMDS positive inputs		
B11, B12, B13, B14 B21, B22, B23, B24 B31, B32, B33, B34 B41, B42, B43, B44	7, 10, 13, 16 117, 120, 123, 126 99, 102, 105, 108 81, 84, 87, 90	I	Source port 1 TMDS negative inputs Source port 2 TMDS negative inputs Source port 3 TMDS negative inputs Source port 4 TMDS negative inputs		

TERMINAL FUNCTIONS (continued)

TERMIN	IAL		
NAME	NO.	I/O	DESCRIPTION
Y11, Y12, Y13, Y14	62, 59, 56, 53	0	Sink port 1 TMDS positive outputs
Y21, Y22, Y23, Y24	43, 40, 37, 34		Sink port 2 TMDS positive outputs
Z11, Z12, Z13, Z14	63, 60, 57, 54	0	Sink port 1 TMDS negative outputs
Z21, Z22, Z23, Z24	44, 41, 38, 35		Sink port 2 TMDS negative outputs
SCL1 SDA1	54	Ю	Source Port 1 DDC I ² C clock line Source Port 1 DDC I ² C data line
SCL2	115	Ю	Source Port 2 DDC I ² C clock line
SDA2	114		Source Port 2 DDC I ² C data line
SCL3	97	IO	Source Port 3 DDC I ² C clock line
SDA3	96		Source Port 3 DDC I ² C data line
SCL4	79	IO	Source Port 4 DDC I ² C clock line
SDA4	78		Source Port 4 DDC I ² C data line
SCL_SINK1	65	IO	Sink port 1 DDC I ² C clock line
SDA_SINK1	66		Sink port 1 DDC I ² C data line
SCL_SINK2	46	Ю	Sink port 2 DDC I ² C clock line
SDA_SINK2	47		Sink port 2 DDC I ² C data line
HPD1	2	0	Source Port 1 hot plug detector output
HPD2	112		Source Port 2 hot plug detector output
HPD3	94		Source Port 3 hot plug detector output
HPD4	76		Source Port 4 hot plug detector output
HPD_SINK1	68	Ι	Sink port 1 hot plug detector input
HPD_SINK2	49		Sink port 2 hot plug detector input
5V_PWR1	3	I	Source Port 1 5-V power signal input
5V_PWR 2	113		Source Port 2 5-V power signal input
5V_PWR 3	95		Source Port 3 5-V power signal input
5V_PWR 4	77		Source Port 4 5-V power signal input
5V_SINK1	67	0	Sink Port 1 5-V power indicator output
5V_SINK 2	48		Sink Port 2 5-V power indicator output
LC_SCL	74	Ю	Local I ² C clock line
LC_SDA	73		Local I ² C data line
LC_A0	72	Ι	Local I ² C address bit 0
LC_A1	71		Local I ² C address bit 1
GE	31	Ι	GPIO Enable L: Local I ² C pins are active, GPIO pins are high impedance H: GPIO pins are active, local I ² C pins are high impedance
GPI00	20	Ι	SA1 – Sink port 1 source selector
GPI01	21		<u>SB1</u> – Sink port 1 source selector
GPI02	22		<u>OE1</u> – Sink port 1 TMDS output enable
GPI03	23		I2CEN1 – Sink port 1 DDC I ² C output enable
GPI04	24		PRE1 – Sink port 1 TMDS AC de-emphasis mode selector
GPI05	25	I	SA2 – Sink port 2 source selector
GPI06	26		SB2 – Sink port 2 source selector
GPI07	27		OE2 – Sink port 2 TMDS output enable
GPI08	28		I2CEN2 – Sink port 2 DDC I ² C output enable
GPI09	29		PRE2 – Sink port 2 TMDS AC de-emphasis mode selector
GPI010	30		SP – Sink priority selector
GPI011	32		OVS – SCL_SINK/SDA_SINK output voltage select
VSADJ	51	I	TMDS compliant voltage swing control
Vcc	1, 9, 15, 19 36, 42, 50, 55, 61 69, 75, 83, 89, 93 101, 107, 111, 119, 125		Power supply
GND	6, 12, 18, 33, 39, 45, 52, 58, 64 70, 80, 86, 92 98, 104, 110, 116, 122, 128		Ground



EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS



Source-Side I2C Input/Output Stage

Sink-Side I2C Input/Output Stage

Status Input Stage





Control Input Stage



Status Output Stage

Control Input Stage







ORDERING INFORMATION⁽¹⁾

PART NUMBER	PART MARKING	PACKAGE
TMDS442PNP	TMDS442	128-PIN TQPF
TMDS442PNPR	TMDS442	128-PIN TQPF Tape/Reel

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

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ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			UNIT
V _{CC} Supply voltage range ⁽²⁾			–0.5 V to 4 V
	Aim*, Bim		2.5 V to 4 V
Voltage range	Yjm, Zjm, , Vsadjj, HPDi, 5V_SINKj,	-0.5V to 4 V	
	SCLi, SCL_SINKj, SDAi, SDA_SINK	–0.5 V to 6 V	
	Human body model ⁽³⁾	Aim, Bim	±6 kV
Electrostatia discharge		All pins	±5 kV
Electrostatic discharge	Charged-device model ⁽⁴⁾ (all pins)	±1500 V	
	Machine model ⁽⁵⁾ (all pins)	±200 V	
Continuous power dissipa	Continuous power dissipation		See Dissipation Rating Table

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltage values, except differential I/O bus voltages, are with respect to network ground terminal. (2)

(3)

Tested in accordance with JEDEC Standard 22, Test Method A114-B Tested in accordance with JEDEC Standard 22, Test Method C101-A (4)

(5) Tested in accordance with JEDEC Standard 22, Test Method A115-A

DISSIPATION RATINGS

PACKAGE	PCB JEDEC STANDARD	T _A ≤ 25°C	DERATING FACTOR ⁽¹⁾ ABOVE $T_A = 25^{\circ}C$	T _A = 70°C POWER RATING
128-TQFP PNP	Low-K ⁽²⁾	2129.47 mW	21.2947 mW/°C	1171.20 mW
128-TQFP PNP	High-K ⁽³⁾	4308.48 mW	43.0848 mW/°C	2369.66 mW

This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow. (1)

In accordance with the Low-K thermal metric definitions of EIA/JESD51-3 (2)

(3) In accordance with the High-K thermal metric definitions of EIA/JESD51-7

THERMAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$R_{\theta JB}$	Junction-to-board thermal resistance			7.86		°C/W
$R_{\theta JC}$	Junction- to-case thermal resistance			19.5		°C/W
P _D	Device power dissipation				1431	mW

RECOMMENDED OPERATING CONDITIONS

		MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	3	3.3	3.6	V
T _A	Operating free-air temperature	0		70	°C
TMDS DIF	FFERENTIAL PINS (A/B)				
V _{IC}	Input common mode voltage	V _{CC} -400		V _{CC} +10	mV
V _{ID}	Receiver peak-to-peak differential input voltage	150		1560	mVp-p
R _{VSADJ}	Resistor for TMDS compliant voltage swing range	4.6	4.64	4.68	kΩ
AV _{CC}	TMDS Output termination voltage, see Figure 3	3	3.3	3.6	V
R _T	Termination resistance, see Figure 3	45	50	55	Ω
	Signaling rate	0		2.25	Gbps
CONTRO	L PINS (LC_A0, LC_A1, GE, GPIO)				
V _{IH}	LVTTL High-level input voltage	2		V _{CC}	V

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RECOMMENDED OPERATING CONDITIONS (continued)

		MIN	NOM MAX	UNIT
V _{IL}	LVTTL Low-level input voltage	GND	0.8	V
CONTR	ROL PINS (OVS)			
VIH	LVTTL High-level input voltage	3	3.6	V
V _{IL}	LVTTL Low-level input voltage	-0.5	0.5	V
STATU	IS PINS (HPD_SINK, 5V_PWR)			
VIH	High-level input voltage	2	5.3	V
VIL	Low-level input voltage	GND	0.8	V
DDC I/C	O PINS (SCL_SINK, SDA_SINK)			
VIH	High-level input voltage	0.7V _{CC}	5.5	V
VIL	Low-level input voltage	-0.5	0.3V _{CC}	V
V _{ILC}	Low-level input voltage contention ⁽¹⁾	-0.5	0.4	V
DDC I/C	O PINS (SCL, SDA)			
V _{IH}	High-level input voltage	2.1	5.5	V
V _{IL}	Low-level input voltage	-0.5	1.5	V
LOCAL	LI ² C PINS (LC_SCL, LC_SDA)			
V _{IH}	High-level input voltage	0.7V _{CC}	V _{CC}	V
VIL	Low-level input voltage	-0.5	0.3V _{CC}	V

(1) V_{IL} specification is for the first low level seen by the SCL_SINK/SDA_SINK lines. V_{ILC} is for the second and subsequent low levels seen by the SCL_SINK/SDA_SINK lines.

ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST COND	ITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
Icc	Supply current		IDMI data pattern,		250 412 ⁽²⁾		mA
P _D	Power dissipation	$ \begin{array}{l} V_{IH}=V_{CC}, \ V_{IL}=V_{CC}-0.4 \ V, \ R_T=50 \ \Omega, \\ AV_{CC}=3.3 \ V, \\ Ai/Bi(2:4)=1.65\text{-}Gbps \ HDMI \ data \ pattern, \\ Ai/Bi(1)=165\text{-}MHz \ Pixel \ clock \end{array} $			640	1344 ⁽²⁾	mW
TMDS DIFF	FERENTIAL PINS (A/B, Y/Z)						
V _{OH}	Single-ended high-level output voltage			AV _{CC} -10		AV _{CC} +10	mV
V _{OL}	Single-ended low-level output voltage			AV _{CC} -600	AV _{CC} -600 A		mV
V _{swing}	Single-ended output swing voltage		2.14	400	400 60		mV
V _{OD(O)}	Overshoot of output differential voltage	R _T = 50 Ω	See Figure 4, $AV_{CC} = 3.3 V$, $B_T = 50 \Omega$		15%		$2 \times V_{swing}$
V _{OD(U)}	Undershoot of output differential voltage				25%		$2 \times V_{swing}$
$\Delta V_{OC(SS)}$	Change in steady-state common-mode output voltage between logic states		-			5	mV
I _{(O)OFF}	Single-ended standby output current	$0 V \le V_{CC} \le 1.5 V,$ $AV_{CC} = 3.3 V, R_T = 50 G.$	2	-10		10	μΑ
V _{OD(pp)}	Peak-to-peak output differential voltage	See Figure 5, PRE = Hi	ab	800		1200	
V _{ODE(SS)}	Steady state output differential voltage with de-emphasis	$AV_{CC} = 3.3 \text{ V}, \text{ R}_{T} = 50 \Omega$		560		840	mVp-p
	Chart arout autout autout		PRE = Low	-12		12	
I _(OS)	Short circuit output current	See Figure 6	PRE = High	-15		15	mA
V _{I(open)}	Single-ended input voltage under high impedance input or open input	I _I = 10 μA		V _{CC} -10		V _{CC} +10	mV
R _{INT}	Input termination resistance	V _{IN} = 2.9 V		45	50	55	Ω
	INS (HPD_SINK, 5V_PWR)		4				

(1)

All typical values are at 25°C and with a 3.3-V supply. The maximum rating is characterized under 3.6 V V_{CC} (2)

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ELECTRICAL CHARACTERISTICS (continued)

over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CON	DITIONS	MIN	TYP ⁽¹⁾ MAX	
		V _{IH} = 5.3 V		-150	15) .
IIH	High-level digital input current	$V_{IH} = 2 V \text{ or } V_{CC}$		-85	8	μA
IIL	Low-level digital input current	V _{IL} = GND or 0.8 V		-20	2) µA
STATUS P	INS (HPD, 5V_SINK)					
V _{OH}	High-level output voltage	I _{OH} = -4 mA		2.4	V _C	v v
V _{OL}	Low-level output voltage	I _{OL} = 4 mA		GND	0.4	4 V
CONTROL	PINS (LC_A0, LC_A1, GE, GPIO)					
I _{IH}	High-level digital input current	$V_{IH} = 2 V \text{ or } V_{CC}$		-10	1) μΑ
IIL	Low-level digital input current	V _{IL} = GND or 0.8 V		-10	1) μΑ
CI	Input capacitance	$V_I = GND \text{ or } V_{CC}$			1) pF
DDC I/O PI	INS (SCL_SINK, SDA_SINK)	1	1			1
		V _I = 5.5 V		-50	50	
l _{lkg}	Input leakage current	$V_{I} = V_{CC}$	-10	1	μΑ	
I _{он}	High-level output current	V _O = 3.6 V		-10	1) µA
IIL	Low-level input current	V _{IL} = GND		-40	4) µA
			OVS = NC	470	62)
V _{OL}	Low-level output voltage	I_{OL} = 400 µA or 4 mA	OVS = GND	620	77	5 V
			$OVS = V_{CC}$	775	95)
			OVS = NC		70	
V _{OL} -V _{ILC}	Low-level input voltage below output low-level voltage level	Ensured by design	OVS = GND		240	mV
	low level voltage level	OVS = V _{CC}			1	
2		V _I = 5.0 V or 0 V, Freq	= 100 kHz		2	5 _
C _{IO}	Input/output capacitance	V _I = 3.0 V or 0 V, Freq	= 100 kHz		1	pF
DDC I/O PI	INS (SCL, SDA) AND LOCAL I ² C PINS (LC	SCL, LC_SDA)	¥			
		V _I = 5.5 V		-50	50) .
l _{lkg}	Input leakage current	$V_{I} = V_{CC}$		-10	1	μΑ
I _{OH}	High-level output current	V _O = 3.6 V		-10	1) µA
l _{iL}	Low-level input current	V _{IL} = GND		-10	1	μΑ
V _{OL}	Low-level output voltage	I _{OL} = 4 mA			0.2	2 V
		V _I = 5.0 V or 0 V, Freq	= 100 kHz		2	5 _
CI	Input capacitance	V _I = 3.0 V or 0 V, Freq	= 100 kHz		1	pF



SWITCHING CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
TMDS D	IFFERENTIAL PINS (Y/Z)		1			
t _{PLH}	Propagation delay time, low-to-high-level output		250		800	ps
t _{PHL}	Propagation delay time, high-to-low-level output		250		800	ps
t _r	Differential output signal rise time (20% - 80%)		80		240	ps
t _f	Differential output signal fall time (20% - 80%)	See Figure 4, AV _{CC} = 3.3 V, R _T = 50 Ω	80		240	ps
t _{sk(p)}	Pulse skew (t _{PHL} - t _{PLH}) ⁽²⁾				50	ps
t _{sk(D)}	Intra-pair differential skew, see Figure 7				75	ps
t _{sk(o)}	Inter-pair channel-to-channel output skew ⁽³⁾				150	ps
t _{sk(bb)}	Bank-to-bank skew				300	ps
t _{sk(pp)}	Part-to-part skew ⁽⁴⁾	_			1	ns
t _{en}	Enable time				20	ns
t _{dis}	Disable time	- See Figure 8			20	ns
t _{sx}	TMDS Switch time				20	ns
t _{jit(pp)}	Peak-to-peak output jitter from Y/Z(1), residual jitter	See Figure 9, Ai/Bi(1) = 165-MHz clock,		10	30	ps
t _{jit(pp)}	Peak-to-peak output jitter from Y/Z(2:4), residual jitter	Ai/Bi(2:4) = 1.65-Gbps HDMI pattern, PRE = low Input: 5m 28AWG HDMI cable, Output: 3-Inch 8-mil trace width		48	74	ps
t _{jit(pp)}	Peak-to-peak output jitter from Y/Z(1), residual jitter	See Figure 9, Ai/Bi(1) = 225-MHz clock,		18	33	ps
t _{jit(pp)}	Peak-to-peak output jitter from Y/Z(2:4), residual jitter	Ai/Bi(2:4) = 2.25-Gbps HDMI pattern, PRE = low Input: 5m 28AWG HDMI cable, Output: 3-Inch 8-mil trace width		56	71	ps
CONTRO	OL AND STATUS PINS (HPD_SINK, HPD, 5V_PWR, 5V_SINK)		1			
t _{pd(HPD)}	Propagation delay time				15	ns
t _{pd(5V)}	Propagation delay time	_			15	ns
t _{sx(HPD)}	HPD Switch time	See Figure 8 C _L = 10 pF, C _{L(DDC)} = 100 pF			15	ns
t _{sx(5V)}	5-V Power switch time	$=$ O_L $=$ 10 pr, $O_L(DDC)$ $=$ 100 pr			15	ns
t _{sx}	DDC Switch time				1	μs
DDC I/O	PINS (SCL, SCL_SINK, SDA, SDA_SINK)					
t _{PLH}	Propagation delay time, low-to-high-level output SCL_SINK/SDA_SINK to SCL/SDA		204		459	ns
t _{PHL}	Propagation delay time, high-to-low-level outputSCL_SINK/SDA_SINK to SCL/SDA		35		140	ns
t _{PLH}	Propagation delay time, low-to-high-level output SCL/SDA to SCL_SINK/SDA_SINK	_	194		351	ns
t _{PHL}	Propagation delay time, high-to-low-level output SCL/SDA to SCL_SINK/SDA_SINK	See Figure 11, OVS = NC	35		140	ns
t _r	Output signal rise time, SCL_SINK/SDA_SINK		500		800	ns
t _f	Output signal fall time, SCL_SINK/SDA_SINK		20		72	ns
tr	Output signal rise time, SCL/SDA		796		999	ns
t _f	Output signal fall time, SCL/SDA		20		72	ns
t _{set}	Enable to start condition		100			ns
t _{hold}	Enable after stop condition	See Figure 12	100			ns

(1) All typical values are at 25°C and with a 3.3-V supply.

(2) $t_{sk(p)}$ is the magnitude of the time difference between t_{PLH} and t_{PHL} of a specified terminal.

(2) t_{sk(p)} is the magnitude of the difference in propagation delay times between any specified terminals of channel 2 to 4 of a device when inputs are tied together.
 (4) t_{sk(pp)} is the magnitude of the difference in propagation delay times between any specified terminals of channel 2 to 4 of two devices, or

(4) t_{sk(pp)} is the magnitude of the difference in propagation delay times between any specified terminals of channel 2 to 4 of two devices, or between channel 1 of two devices, when both devices operate with the same source, the same supply voltages, at the same temperature, and have identical packages and test circuits.



TIMING CHARACTERISTICS FOR LOCAL I²C INTERFACE (LC_SCL, LC_SDA, LC_AO, LC_A1)

	PARAMETER	STANDARD	MODE	FAST M	ODE	
	PARAMETER	MIN	MAX	MIN	MAX	UNIT
f _{SCL}	Clock frequency, SCL		100		400	kHz
t _{w(L)}	Clock low period, SCL low	4.7		1.3		μs
t _{w(H)}	Clock high period, SCL high	4		0.6		μs
t _r	Rise time, SCL and SDA		1000		300	μs
t _f	Fall time, SCL and SDA		300		300	μs
t _{su(1)}	Setup time, SDA to SCL	250		100		μs
t _{h(1)}	Hold time, SCL to SDA	0		0		μs
t _(buf)	BUS Free time between a STOP and START condition	4.7		1.3		μs
t _{su(2)}	Setup time, SCL to start condition	4.7		0.6		μs
t _{h(2)}	Hold time, start condition to SCL	4		0.6		μs
t _{su(3)}	Setup time, SCL to stop condition	4		0.6		μs
C _b ⁽¹⁾	Capacitive load for each bus line		400		400	pF

(1) C_b is the total capacitance of one bus line in pF.





A. t_r and t_f are measured at 20% - 80% refered to V_{IHmin} and V_{ILmax} levels.

Figure 1. SCL and SDA Timing



Figure 2. Start and Stop Conditions



Figure 3. Typical Termination for TMDS Output Driver



PARAMETER MEASUREMENT INFORMATION (continued)

NOTE: PRE = low. All input pulses are supplied by a generator having the following characteristics: t_r or t_f < 100 ps, 100 MHz from Agilent 81250. C_L includes instrumentation and fixture capacitance within 0.06 m of the D.U.T. Measurement equipment provides a bandwidth of 20 GHz minimum.

Figure 4. TMDS Timing Test Circuit and Definitions





Figure 5. De-Emphasis Output Voltage Waveforms and Duration Measurement Definitions



Figure 6. Short Circuit Output Current Test Circuit



Figure 7. Definition of Intra-Pair Differential Skew





PARAMETER MEASUREMENT INFORMATION (continued)

Figure 8. TMDS Outputs Control Timing Definitions



A. All jitters are measured in BER of 10⁻¹²

B. The residual jitter reflects the total jitter measured at the TMDS442 output, TP3, subtract the total jitter from the signal generator, TP1

C. The input cable length and the output transmission media are specified in the test conditions.

Figure 9. Jitter Test Circuit





PARAMETER MEASUREMENT INFORMATION (continued)





PARAMETER MEASUREMENT INFORMATION (continued)





TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS (continued)





TYPICAL CHARACTERISTICS (continued)





TYPICAL CHARACTERISTICS (continued)



Figure 22. Eye Patterns at 148.5-MHz Pixel Clock



DESCRIPTION

SOURCE SELECTION LOOKUP

CC	ONTROL	REGIST	ER BITS	I/O	SELECTED		HOT PLUG DE	TECT STATUS	
SB	SA	ŌĒ	I2CEN	Y/Z	SCL_SINK SDA_SINK	HPD1	HPD2	HPD3	HPD4
L	L	L	Н	A1/B1	SCL1 SDA1	HPD_SINK	L	L	L
L	Н	L	Н	A2/B2	SCL2 SDA2	L	HPD_SINK	L	L
Н	L	L	Н	A3/B3	SCL3 SDA3	L	L	HPD_SINK	L
Н	Н	L	Н	A4/B4	SCL4 SDA4	L	L	L	HPD_SINK
Х	Х	L	L	A/B	Z	HPD_SINK is trai	nsmitted to corres	ponding source p	oort
Х	Х	н	Н	Z	SCL SDA	HPD_SINK is trai	nsmitted to corres	ponding source p	oort
Х	Х	Н	L	Z	Z	HPD_SINK is trai	nsmitted to corres	ponding source p	oort

SINK PRIORITY CONTROL (SA1 = SA2 = Low, SB1 = SB2 = Low, OE1 = OE2 = Low, I2CEN1 = I2CEN2 = High)

SINK PRIORITY	:	SINK PORT 1		SINK PORT 2			
SP	Y1/Z1 SCL_SINK1/SDA_SINK1		Y2/Z2	Y2/Z2 SCL_SINK2/SDA_SINK2			
L	A1/B1	A1/B1 SCL1/SDA1		Z	HPD_SINK1		
Н	A1/B1	Z	A1/B1	SCL1/SDA1	HPD_SINK2		

5V_PW<u>R</u> STATUS (SA = Low, SB = Low, OE = Low, I2CEN = High)

	CONTROL STATUS SOURCE PLUG IN STATUS		1/0	D SELECTED	HOT PLUG DETECT STATUS			
GE	5V_EN	5V_PWR1	Y/Z	SCL_SINK/SDA_SINK	HPD1	HPD2	HPD3	HPD4
L	Н	Н	A1/B1	SCL1/SDA1	HPD_SINK	L	L	L
L	Н	L	Z	Z	L	L	L	L
L	L	Х	A1/B1	SCL1/SDA1	HPD_SINK	L	L	L
Н	Х	Н	A1/B1	SCL1/SDA1	HPD_SINK	L	L	L
Н	Х	L	Z	Z	L	L	L	L

I²C POINTER REGISTER

P7	P6	P5	P4	P3	P2	P1	P0
0	0	0	0	0	0	Х	Х

01, Sink port 1 configuration register

10, Sink port 2 configuration register

11, Source plug-in status register

Power up default is 0000 0011



SINK PORT 1 CONFIGURATION REGISTER

C7	C6	C5	C4	C3	C2	C1	C0
0	0	0	PRE1	I2CEN1	OE1	SB1	SA1

Power up default is 0000 1000

SINK PORT 2 CONFIGURATION REGISTER

C7	C6	C5	C4	C3	C2	C1	C0
0	0	0	PRE2	I2CEN2	OE2	SB2	SA2

Power up default is 0000 1001

SOURCE PLUG-IN STATUS REGISTER

S7	S6	S5	S4	S3	S2	S1	S0
0	0	SP	5V_EN	5V_PWR4	5V_PWR3	5V_PWR2	5V_PWR1

Power up default is 0001 0000

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APPLICATION INFORMATION

I²C Interface Notes

The I²C interface is used to access the internal registers of the TMDS442. I²C is a two-wire serial interface developed by Philips Semiconductor (see I²C-Bus Specification, Version 2.1, January 2000). The bus consists of a data line (SDA) and a clock line (SCL) with pull-up structures. When the bus is idle, both SDA and SCL lines are pulled high. All the I²C compatible devices connect to the I²C bus through open drain I/O pins, SDA and SCL. A master device, usually a microcontroller or a digital signal processor, controls the bus. The master is responsible for generating the SCL signal and device addresses. The master also generates specific conditions that indicate the START and STOP of data transfer. A slave device receives and/or transmits data on the bus under control of the master device. The TMDS442 works as a slave and supports the standard mode transfer (100 kbps) and fast mode transfer (400 kbps) as defined in the I²C-Bus Specification. The TMDS442 has been tested to be fully functional with the high-speed mode (3.4 Mbps) but is not ensured at this time.

The basic I²C start and stop access cycles are shown in Figure 23. The basic access cycle consists of the following:

- A start condition
- A slave address cycle
- Any number of data cycles
- A stop condition



Figure 23. I²C Start and Stop Conditions

General I²C Protocol

- The master initiates data transfer by generating a start condition. The start condition is when a high-to-low transition occurs on the SDA line while SCL is high, as shown in Figure 23. All I²C-compatible devices should recognize a start condition.
- The master then generates the SCL pulses and transmits the 7-bit address and the read/write direction bit R/W on the SDA line. During all transmissions, the master ensures that data is valid. A valid data condition requires the SDA line to be stable during the entire high period of the clock pulse (see Figure 23). All devices recognize the address sent by the master and compare it to their internal fixed addresses. Only the slave device with a matching address generates an acknowledge (see Figure 25) by pulling the SDA line low during the entire high period of the ninth SCL cycle. On detecting this acknowledge, the master knows that a communication link with a slave has been established.
- The master generates further SCL cycles to either transmit data to the slave (R/W bit 1) or receive data from the slave (R/W bit 0). In either case, the receiver needs to acknowledge the data sent by the transmitter. So an acknowledge signal can either be generated by the master or by the slave, depending on which one is the receiver. The 9-bit valid data sequences consisting of 8-bit data and 1-bit acknowledge can continue as long as necessary (see Figure 26).
- To signal the end of the data transfer, the master generates a stop condition by pulling the SDA line from low
 to high while the SCL line is high (see Figure 23). This releases the bus and stops the communication link
 with the addressed slave. All I²C compatible devices must recognize the stop condition. Upon the receipt of a
 stop condition, all devices know that the bus is released, and they wait for a start condition followed by a
 matching address.





Figure 24. I²C Bit Transfer



Figure 26. I²C Address and Data Cycles

During a write cycle, the transmitting device must not drive the SDA signal line during the acknowledge cycle so that the receiving device may drive the SDA signal low. After each byte transfer following the address byte, the receiving device will pull the SDA line low for one SCL clock cycle. A stop condition will be initiated by the transmitting device after the last byte is transferred. An example of a write cycle can be found in Figure 27 and Figure 28. Note that the TMDS442 does not allow multiple write transfers to occur. See Example – Writing to the TMDS442 section for more information.

During a read cycle, the slave receiver will acknowledge the initial address byte if it decodes the address as its address. Following this initial acknowledge by the slave, the master device becomes a receiver and

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acknowledges data bytes sent by the slave. When the master has received all of the requested data bytes from the slave, the not acknowledge (A) condition is initiated by the master by keeping the SDA signal high just before it asserts the stop (P) condition. This sequence terminates a read cycle as shown in Figure 29 and Figure 30. Note that the TMDS442 does not allow multiple read transfers to occur. See Example – Reading from the TMDS442 section for more information.



Slave Address

Both SDA and SCL must be connected to a positive supply voltage via a pull-up resistor. These resistors should comply with the I²C specification that ranges from 2 k Ω to 19 k Ω . When the bus is free, both lines are high. The address byte is the first byte received following the START condition from the master device. The first 5 Bits (MSBs) of the address are factory preset to 01011. The next two bits of the TMDS442 address are controlled by

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the logic levels appearing on the I2C-A1 and I2C-A0 pins. The I2C-A1 and I2C-A0 address inputs can be connected to V_{CC} for logic 1, GND for logic 0, or can be actively driven by TTL/CMOS logic levels. The device addresses are set by the state of these pins and are not latched. Thus a dynamic address control system could be utilized to incorporate several devices on the same system. Up to four TMDS442 devices can be connected to the same I²C-Bus without requiring additional glue logic. Table 1 lists the possible addresses for the TMDS442.

	FIXED	ADDRESSE	S		SELECTABLE WITH	READ/WRITE BIT	
BIT 7 (MSB)	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2 (A1)	BIT 1 (A0)	BIT 0 (R/W)
0	1	0	1	1	0	0	0
0	1	0	1	1	0	0	1
0	1	0	1	1	0	1	0
0	1	0	1	1	0	1	1
0	1	0	1	1	1	0	0
0	1	0	1	1	1	0	1
0	1	0	1	1	1	1	0
0	1	0	1	1	1	1	1

Table 1. TMDS442 Slave Addresses

Sink Port Selection Register and Source Plug-In Status Register Description (Sub-Address)

The TMDS442 operates using only a single byte transfer protocol similar to Figure 27 and Figure 29. The internal sub-address registers and the functionality of each can be found in Table 2. When writing to the device, it is required to send one byte of data to the corresponding internal sub-address. If control of two sink ports and source plug-in status is desired, then the master will have to cycle through the sub-addresses (sink ports) one at a time as illustrated in the Example – Writing to the TMDS442 section for the proper procedure of writing to the TMDS442.

During a read cycle, the TMDS442 sends the data in its selected sub-address in a single transfer to the master device requesting the information. See the Example – Reading from the TMDS442 section of this document for the proper procedure on reading from the TMDS442. Upon power up, the TMDS442 registers are in a default value, 0000 0011.

Table 2. TMDS442 Sink Port and Source Plug-In Status Registers Selection

REGISTER NAME	BIT ADDRESS (b ₇ b ₆ b ₅ b ₀)
Sink port 1	0000 0001
Sink port 2	0000 0010
Source plug-in status	0000 0011

Sink Port Register Bit Descriptions

Each bit of the first two sub-addresses, sink port 1 and port 2 control registers, allows the user to individually control the functionality of the TMDS442. The benefit of this process allows the user to control the functionality of each sink port independent of the other sink port. The bit description is decoded in Table 3.

BIT	FUNCTION	BIT VALUES	RESULT
7, 6, 5	Reserved	000	Default value
4		0	3dB De-emphasis off
4	PRE	1	3dB De-emphasis on
2		0	Sink side I ² C buffer is disabled (Hi-Z)
3	I2CEN	1	Sink side I ² C buffer is enabled
2	05	0 Sink side TMDS on	
2	OE	1	Sink side TMDS off (Hi-Z)

Table 3. TMDS442 Sink Port Register Bit Decoder



Table 3. TMDS442 Sink Port Register Bit Decoder (continued)

BIT	FUNCTION	BIT VALUES	RESULT
		00	Source port 1 select
1.0	SB SA	01	Source port 2 select
1, 0	36 3A	10	Source port 3 select
		11	Source port 4 select

Bits 7 (MSB), 6 and 5 – Reserved bits without function.

Bit 4 – Controls the TMDS output differential voltage.

Bit 3 – Controls the status of DDC interface, SCL_SINK and SDA_SINK.

Bit 2 – Controls the status of TMDS interface, Y/Z.

Bits 1, and 0 (LSB) – Selects the source input of the TMDS442.

The 5-V plug in status can be read through each bit of the sub-address (source plug-in status) status register. Each bit of the third sub-address, source plug-in status registers, allows the user to read the cable plug-in status based on the appearance of a valid +5-V power signal from each source input port. The bit description is decoded in Table 4.

BIT	FUNCTION	BIT VALUES	RESULT
7, 6	Reserved	0 0	Default value
F	SP	0	Sink port1 is the main display when the same source is selected by both sinks
5	58	1	Sink port2 is the main display when the same source is selected by both sinks
4		0	TMDS output status is not controlled by the corresponding +5-V power signal
4 5V_EN	1	TMDS output status is controlled by the corresponding +5-V power signal	
		0	Source side I ² C buffer is disabled (Hi-Z) When source port 4 is selected by sink, TMDS is Hi-Z
3	5V_PWR4	1	Source side I ² C buffer is enabled When source port 4 is selected by sink, TMDS is under the control of $\overline{\text{OE}}$
2		0	Source side I ² C buffer is disabled (Hi-Z)
2	5V_PWR3	1	When source port 3 is selected by sink, TMDS is Hi-Z
		0	Source side I ² C buffer is disabled (Hi-Z) When source port 2 is selected by sink, TMDS is Hi-Z
1	5V_PWR2	1	Source side I ² C buffer is enabled When source port 2 is selected by sink, TMDS is under the control of $\overline{\text{OE}}$
0		0	Source side I^2C buffer is disabled (Hi-Z) When source port 1 is selected by sink, TMDS is Hi-Z
0	5V_PWR1	1	Source side I ² C buffer is enabled When source port 1 is selected by sink, TMDS is under the control of $\overline{\text{OE}}$

Table 4. TMDS442 Source Plug-In Status Register Bit Decoder

Example - Writing to the TMDS442

The proper way to write to the TMDS442 is illustrated as follows:

An I²C master initiates a write operation to the TMDS442 by generating a start condition (S) followed by the TMDS442 I²C address (as shown below), in MSB first bit order, followed by a 0 to indicate a write cycle. After receiving an acknowledge from the TMDS442, the master presents the sub-address (sink port) it wants to write consisting of one byte of data, MSB first. The TMDS442 acknowledges the byte after completion of the transfer. Finally the master presents the data it wants to write to the register (sink port) and the TMDS442 acknowledges the byte. The I²C master then terminates the write operation by generating a stop condition (P). Note that the TMDS442 does not support multi-byte transfers. To write to both sink ports – or registers - this procedure must be repeated for each register one series at a time (i.e. repeat steps 1 through 8 for each sink port).

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STEP 1	0							
I ² C Start (Master)	S							
STEP 2	7	6	5	4	3	2	1	0
I ² C General Address (Master)	0	1	0	1	1	Х	Х	0

Where each X logic state is defined by I2C-A1 and I2C-A0 pins being tied to either Vs+ or GND.

STEP 3	9							
I ² C Acknowledge (Slave)	А							
STEP 4	7	6	5	4	3	2	1	0
I ² C Write Sink Port Address (Master)	0	0	0	0	0	0	Addr	Addr

Where Addr is determined by the values shown in Table 2.

STEP 5	9							
I ² C Acknowledge (Slave)		А						
STEP 6	7	6	5	4	3	2	1	0
I ² C Write Data (Master)	Data							

Where Data is determined by the values shown in Table 3.

STEP 7	9
I ² C Acknowledge (Slave)	А
	1
STEP 8	0
I ² C Stop (Master)	Р

For step 4, an example of the proper bit control for selecting sink port 2 is 0000 0010.

For step 6, an example of the proper bit control for selecting source port B, enabling TMDS outputs and DDC link of the sink port 2 without 3.5dB de-emphasis is 0000 1001.

Example - Reading From the TMDS442

The read operation consists of two phases. The first phase is the address phase. In this phase, an I²C master initiates a write operation to the TMDS442 by generating a start condition (S) followed by the TMDS442 I²C address, in MSB first bit order, followed by a 0 to indicate a write cycle. After receiving acknowledges from the TMDS442, the master presents the sub-address (sink port) of the register it wants to read. After the cycle is acknowledged (A), the master terminates the cycle immediately by generating a stop condition (P).

The second phase is the data phase. In this phase, an I²C master initiates a read operation to the TMDS442 by generating a start condition followed by the TMDS442 I²C address (as shown below for a read operation), in MSB first bit order, followed by a 1 to indicate a read cycle. After an acknowledge from the TMDS442, the I²C master receives one byte of data from the TMDS442. After the data byte has been transferred from the TMDS442 to the master, the master generates a NOT-acknowledge followed by a stop. Similar to the write function, to read both sink ports steps 1 through 11 must be repeated for each and every sink port desired.

TMDS Read Phase 1:

STEP 1	0							
I ² C Start (Master)	S							
STEP 2	7	6	5	4	3	2	1	0
I ² C General Address (Master)	0	1	0	1	1	Х	Х	0

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Where each X logic state is defined by I2C-A1 and I2C-A0 pins being tied to either Vs+ or GND.

STEP 3	9							
I ² C Acknowledge (Slave)	А							
STEP 4	7	6	5	4	3	2	1	0
I ² C Read Sink Port Address (Master)	0	0	0	0	0	0	Addr	Add

Where Addr is determined by the values shown in Table 2.

STEP 5	9
I ² C Acknowledge (Slave)	А
STEP 6	0
I ² C Stop (Master)	Р

TMDS442 Read Phase 2:

STEP 7	0							
I ² C Start (Master)	S							
STEP 8	7	6	5	4	3	2	1	0
I ² C General Address (Master)	0	1	0	1	1	Х	Х	1

Where X logic state is defined by I2C-A1 and I2C-A0 pins being tied to either Vs+ or GND.

STEP 9	9							
I ² C Acknowledge (Slave)	А							
STEP 10	7	6	5	4	3	2	1	0
I ² C Read Data (Slave)	Data							

Where Data is determined by the logic values contained in the Sink Port Register.

STEP 11	9
I ² C Not-Acknowledge (Master)	А
·-	
STEP 12	0
I ² C Stop (Master)	Р

Supply Voltage

All V_{CC} pins can be tied to a single 3.3-V power source. A 0.01- μ F capacitor is connected from each V_{CC} pin directly to ground to filter supply noise.

TMDS Inputs

Standard TMDS terminations are integrated on all TMDS inputs. External terminations are not required. Each input channel contains an 8-dB equalization circuit to compensate for cable losses. The voltage at the TMDS input pins must be limited per the absolute maximum ratings. An unused input should not be connected to ground as this would result in excessive current flow damaging the device. TMDS input pins do not incorporate failsafe circuits. An unused input channel can be externally biased to prevent output oscillation. The complementary input pin is recommended to be grounded through a $1-k\Omega$ resistor and the other pin left open.

TMDS Outputs

A 1% precision resister, 4.64-k Ω , connected from VSADJ to ground is recommended to allow the differential output swing to provide TMDS signal levels. The differential output driver provides a typical 10-mA current sink capability, which provides a typical 500-mV voltage drop across a 50- Ω termination resistor. A 10% accuracy resistor is allowed to be connected when the output swing is not strictly required to meet the TMDS signal levels. A 10% resistor provides differential output voltages in the range of 438 mV and 532 mV.



Figure 31. TMDS Driver and Termination Circuit

Referring to Figure 31, if both V_{CC} (TMDS442 supply) and AV_{CC} (sink termination supply) are both powered, the TMDS output signals are high impedance when \overline{OE} = high. Both supplies being active is the normal operating condition.

Again refer to Figure 31, if V_{CC} is on and AV_{CC} is off, the TMDS outputs source a typical 5-mA current through each termination resistor to ground. A total of 10-mW of power is consumed by the terminations independent of the \overline{OE} logical selection. When AV_{CC} is powered on, normal operation (\overline{OE} controls output impedance) is resumed.

When the power source of the device is off and the power source to termination is on, the $I_{O(off)}$, output leakage current, specification ensures the leakage current is limited 10-µA or less.

The PRE pin provides 3dB de-emphasis, allowing output signal pre-conditioning to offset interconnect losses from the TMDS442 outputs to a TMDS receiver. PRE is recommended to be set low while connecting to a receiver throw short PCB route.

HPD Pins

The HPD signals (HPD1, HPD2, HPD3) have an output impedance of 47- Ω typically. In certain applications, a 931- Ω resistor from the HPD output to the connector pin is recommended, to increase the output resistance to 1-K Ω +/- 20%.

DDC Channels

The DDC channels are designed using I^2C drivers with 5-V signal tolerance, allowing direct connection to standard I^2C buses.

Dual-Link 2-to-1 Switch Configurations

TMDS442 can be simply configured to operate as a dual-link DVI/HDMI, 2-to-1 switch, by configuring the device as follows, see Figure 32:

- 1. Set SA1 = low and SA2 = high
- 2. Set SB1 = SB2
- 3. When the 5V_SINK1, HPD_SINK1, SCL_SINK1, and SDA_SINK1 are selected as the control channels from/to the SINK, connect the 5V_PWR1, HPD1, SCL1, and SDA1 to the dual-link source 1, and connect the 5V_PWR3, HPD3, SCL3, and SDA3 to the dual-link source 2.
- 4. When the 5V_SINK2, HPD_SINK2, SCL_SINK2, and SDA_SINK2 are selected as the control channels from/to the SINK, connect the 5V_PWR2, HPD2, SCL2, and SDA2 to the dual-link source 1, and connect the 5V_PWR4, HPD4, SCL4, and SDA4 to the dual-link source 2.

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Figure 32. Dual-Link 2-to-1 DVI/HDMI Switch Configuration

In a dual link application, the unused TMDS input should be configured as follows: the complementary input pin is grounded through a 1-k Ω resistor, and the other pin left open.

Layout Considerations

The high-speed TMDS inputs are the most critical paths for the TMDS442. There are several considerations to minimize discontinuities on these transmission lines between the connectors and the device:

- The TMDS differential inputs should be layout in the shortest stubs from connectors directly
- Maintain 100- Ω differential impedance into and out of the TMDS442
- Keep an uninterrupted ground plane beneath the high-speed I/Os
- Keep the ground-path vias to the device as close as possible to allow the shortest return current path

I²C Function Description

The SCL/SDA and SCL_SINK/SDA_SINK pins are 5-V tolerant when the device is powered off and high impedance under low supply voltage, 1.5 V or below. If the device is powered up and the I^2C circuits are enabled, and EN = high, the driver T (see Figure 33) is turned on or off depending up on the corresponding R side voltage level.

When the R side is pulled low below 1.5 V, the corresponding T side driver turns on and pulls the T side down to a low level output voltage, V_{OL} . The value of V_{OL} depends on the input to the OVS pin. When OVS is left floating

or not connected, V_{OL} is typically 0.5 V. When OVS is connected to GND, V_{OL} is typically 0.65 V. When OVS is connected to V_{CC} , V_{OL} is typically 0.8 V. V_{OL} is always higher than the driver R input threshold, V_{IL} , which is typically 0.4 V, preventing lockup of the repeater loop. The V_{OL} value can be selected to improve or optimize noise margins between V_{OL} and the V_{IL} of the repeater itself or the V_{IL} of some external device connected on the T side.

When the R side is pulled up, above 1.5 V, the T side driver turns off and the T side pin is high impedance.



Figure 33. I²C Drivers in TMDS442

When the T side is pulled below 0.4 V by an external I^2C driver, both drivers R and T are turned on. Driver R pulls the R side to near 0 V, and driver T is on, but is overridden by the external I^2C driver. If driver T is already on, due to a low on the R side, driver R just turns on.

When the T side is released by the external I²C driver, driver T is still on, so the T side is only able to rise to the V_{OL} of driver T. Driver R turns off, since V_{OL} is above its 0.4-V V_{IL} threshold, releasing the R side. If no external I²C driver is keeping the R side low, the R side rises, and driver T turns off once the R side rises above 1.5 V, see Figure 34.



Figure 34. Waveform of Turning Driver T Off

It is important that any external I^2C driver on the T side is able to pull the bus below 0.4 V to ensure full operation. If the T side cannot be pulled below 0.4 V, driver R may not recognize and transmit the low value to the R side.

I²C Enable

The I2C drivers are enabled with an internal EN signal. This EN signal is the AND gate result of the 5V_PWR signal from the selected input port and the I2CEN signal for the output. This AND gate is turned on based on an OR gate result of the GE and the 5V_EN settings.



Figure 35. I²C Enable Equivalent Logic

When GE sets high, or GE sets low and 5V_EN sets high, the EN signal is the AND result of the 5V_PWR and the I2CEN. When GE sets low and 5V_EN sets low, the EN signals follows the status of I2CEN. See Table 5.

GE	5V_EN ⁽¹⁾	5V_PWR	I2CEN	EN
1	Х	1	1	1
1	Х	1	0	0
1	Х	0	1	0
1	Х	0	0	0
0	1	1	1	1
0	1	1	0	0
0	1	0	1	0
0	1	0	0	0
0	0	1	1	1
0	0	1	0	0
0	0	0	1	1
0	0	0	0	0

Table 5. Truth Table for the EN Signal of the I²C Driver

(1) X is 1 or 0

The I2CEN pin is active-high with an internal pull-up to V_{CC} . It can be used to isolate a badly behaved slave during powering up. It should never change state during an I²C operation because disabling during a bus operation may hang the bus and enabling part way through a bus cycle could confuse the I²C parts being enabled.

I²C Behavior

The typical application of the TMDS442 is as a repeater in a TV connecting the HDMI input connector and an internal HDMI Rx through flat cables. The I²C repeater is 5-V tolerant, and no additional circuitry is required to translate between 3.3-V to 5-V bus voltages. In the following example, the system master is running on an R-side I²C-bus while the slave is connected to a T-side bus. Both buses run at 100 kHz supporting standard-mode I²C operation. Master devices can be placed on either bus.





Figure 37 illustrates the waveforms seen on the R-side I^2C -bus when the master writes to the slave through the I^2C repeater circuit of the TMDS442. This looks like a normal I^2C transmission, and the turn on and turn off of the acknowledge signals are slightly delayed.



Figure 37. Bus R Waveform

Figure 38 illustrates the waveforms seen on the T-side I²C-bus under the same operation in Figure 37. On the T-side of the I²C repeater, the clock and data lines would have a positive offset from ground equal to the V_{OL} of the driver T. After the 8th clock pulse, the data line is pulled to the V_{OL} of the slave device which is very close to ground in this example. At the end of the acknowledge, the slave device releases and the bus level rises back to the V_{OL} set by the driver until the R-side rises above $V_{CC}/2$, after which it continues to high. It is important to note that any arbitration or clock stretching events require that the low level on the T-side bus at the input of the TMDS442 I²C repeater is below 0.4 V to be recognized by the device and then transmitted to the R-side I²C bus.



Figure 38. Bus T Waveform

The I²C circuitry inside the TMDS442 allows multiple stage operation as shown in Figure 39. I²C-Bus slave devices can be connected to any of the bus segments. The number of devices that can be connected in series is limited by repeater delay/time of flight considerations for the maximum bus speed requirements.



Figure 39. Typical Series Application

I²C Pull-up Resistors

The pull-up resistor value is determined by two requirements:

1. The maximum sink current of the I^2C buffer:

The maximum sink current is 3 mA or slightly higher for an I^2C driver supporting standard-mode I^2C operation,.

 $R_{up(min)} = V_{DD}/lsink$

 The maximum transition time on the bus: The maximum transition time, T, of an I²C bus is set by an RC time constant, where R is the pull-up resistor

(1)

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value, and C is the total load capacitance. The parameter, k, can be calculated from equation 3 by solving for t, the times at which certain voltage thresholds are reached. Different input threshold combinations introduce different values of t. Table 6 summarizes the possible values of k under different threshold combinations. $T = k \times RC$ (2)

$$V(t) = V_{DD}(1 - e^{-t/RC})$$

(3)

JMENTS

				•	•		0		
$V_{th-}V_{th+}$	$0.7V_{DD}$	$0.65V_{DD}$	0.6V _{DD}	$0.55V_{DD}$	$0.5V_{DD}$	0.45V _{DD}	$0.4V_{DD}$	0.35V _{DD}	0.3V _{DD}
$0.1 V_{DD}$	1.0986	0.9445	0.8109	0.6931	0.5878	0.4925	0.4055	0.3254	0.2513
$0.15V_{DD}$	1.0415	0.8873	0.7538	0.6360	0.5306	0.4353	0.3483	0.2683	0.1942
$0.2V_{DD}$	0.9808	0.8267	0.6931	0.5754	0.4700	0.3747	0.2877	0.2076	0.1335
$0.25V_{DD}$	0.9163	0.7621	0.6286	0.5108	0.4055	0.3102	0.2231	0.1431	0.0690
0.3V _{DD}	0.8473	0.6931	0.5596	0.4418	0.3365	0.2412	0.1542	0.0741	-

Table 6. Value K Upon Different Input Threshold Voltages

From equation 1, $R_{up(min)} = 5.5V/3mA = 1.83 k\Omega$ to operate the bus under a 5-V pull-up voltage and provide less than 3 mA when the I²C device is driving the bus to a low state. If a higher sink current, for example 4 mA, is allowed, $R_{up(min)}$ can be as low as 1.375 k Ω .

Given a 5-V I²C device with input low and high threshold voltages at 0.3 V_{dd} and 0.7 V_{dd}, the valued of k is 0.8473 from Table 6. Taking into account the 1.83-k Ω pull-up resistor, the maximum total load capacitance is C_(total-5V) = 645 pF. C_{cable(max)} should be restricted to be less than 545 pF if C_{source} and C_i can be as heavy as 50 pF. Here the C_i is treated as C_{sink}, the load capacitance of a sink device.

Fixing the maximum transition time from Table 6, T = 1 μ s, and using the k values from Table 6, the recommended maximum total resistance of the pull-up resistors on an I²C bus can be calculated for different system setups.

To support the maximum load capacitance specified in the HDMI spec, $C_{cable(max)} = 700 \text{pF/}C_{source} = 50 \text{pF/}C_i = 50 \text{pF}, R_{(max)}$ can be calculated as shown in Table 7.

$V_{th} V_{th+}$	$0.7V_{DD}$	$0.65V_{DD}$	0.6V _{DD}	$0.55V_{DD}$	$0.5V_{DD}$	$0.45V_{DD}$	$0.4V_{DD}$	$0.35V_{DD}$	$0.3V_{DD}$	UNIT
0.1V _{DD}	1.14	1.32	1.54	1.80	2.13	2.54	3.08	3.84	4.97	kΩ
0.15V _{DD}	1.20	1.41	1.66	1.97	2.36	2.87	3.59	4.66	6.44	kΩ
$0.2V_{DD}$	1.27	1.51	1.80	2.17	2.66	3.34	4.35	6.02	9.36	kΩ
$0.25V_{DD}$	1.36	1.64	1.99	2.45	3.08	4.03	5.60	8.74	18.12	kΩ
0.3V _{DD}	1.48	1.80	2.23	2.83	3.72	5.18	8.11	16.87	-	kΩ

Table 7. Pull-Up Resistor Upon Different Threshold Voltages and 800-pF Loads

Or, limiting the maximum load capacitance of each cable to be 400 pF to accommodate with I²C spec version 2.1. $C_{cable(max)} = 400 pF/C_{source} = 50 pF/C_i = 50 pF$, the maximum values of R are calculated as shown in Table 8.

Table 8. Pull-Up Resistor Upon Different Threshold Voltages and 500-pF Loads

V _{th-} \V _{th+}	$0.7V_{DD}$	$0.65V_{DD}$	$0.6V_{DD}$	$0.55V_{DD}$	$0.5V_{DD}$	$0.45V_{DD}$	$0.4V_{DD}$	$0.35V_{DD}$	$0.3V_{DD}$	UNIT
$0.1 V_{DD}$	1.82	2.12	2.47	2.89	3.40	4.06	4.93	6.15	7.96	kΩ
0.15V _{DD}	1.92	2.25	2.65	3.14	3.77	4.59	5.74	7.46	10.30	kΩ
0.2V _{DD}	2.04	2.42	2.89	3.48	4.26	5.34	6.95	9.63	14.98	kΩ
0.25V _{DD}	2.18	2.62	3.18	3.92	4.93	6.45	8.96	13.98	28.99	kΩ
0.3V _{DD}	2.36	2.89	3.57	4.53	5.94	8.29	12.97	26.99	-	kΩ

Obviously, to accommodate the 3-mA drive current specification, a narrower threshold voltage range is required to support a maximum 800-pF load capacitance for a standard-mode I²C bus.

When the input low and high level threshold voltages, V_{th-} and V_{th+} , are 0.7 V and 1.9 V, which is 0.15 V_{DD} and 0.4 V_{DD} approximately with $V_{DD} = 5$ V, from Table 7, the maximum pull-up resistor is 3.59 k Ω . The allowable pull-up resistor is in the range of 1.83 k Ω and 3.59 k Ω .



Thermal Dissipation

High-K board – It is always recommended to solder the PowerPAD[™] onto the thermal land. A thermal land is the area of solder-tinned-copper underneath the PowerPAD package. Thermal simulation shows the θJA of the TMDS442 is 23.2°C/W on a high-K board with a 4 x 4 thermal via array, or is 29.4°C/W under the same condition without a via array. The maximum junction temperature is 103°C with via arrays and 112°C without via arrays when the maximum power dissipation from the device is 1.43W. The maximum recommended junction temperature is 125°C, allowing the TMDS442 to operate over the full temperature range (0°C - 70°C) when the PowerPAD is soldered onto the thermal land.

Low-K board – Simulation also shows the θ JA of the TMDS442 is 46.9°C/W on a low-K board with the PowerPAD soldered and no thermal vias. To ensure the maximum junction temperature does not exceed 125°C with a worst case power dissipation from the device of 1.43W, the ambient temperature needs to be lower than 58°C, when the device is placed on a low-K board.

A general PCB design guide to PowerPAD package is provided in slma002 - PowerPAD Thermally Enhanced Package.

PACKAGE OPTION ADDENDUM

PACKAGING INFORMATION 30-August-2006

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TMDS442PNP	ACTIVE	HTQFP	PNP	128	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
TMDS442PNPG4	ACTIVE	HTQFP	PNP	128	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR

1. The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available. **OBSOLETE:** TI has discontinued the production of the device.

2. Eco Plan -The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) -please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

3. MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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Revision History

Changes from Original (August 2006) to Revision A

•	Changed HDMI 1.3 to HDMI 1.3a	1
•	Changed 1.65 Gbps to 2.25 Gbps and 8-Bit to 12-Bit	1
•	Changed 1.65 Gbps to 2.25 Gbps	1
•	Changed 1.65 Gbps to 2.25 Gbps	7
•	Added 2.25 Gbps Peak-to-peak output jitter from Y/Z(1), residual jitter	10
•	Added 2.25 Gbps Peak-to-peak output jitter from Y/Z(2:4), residual jitter	10
•	Changed RESIDUAL PEAK-TO-PEAK JITTER vs DATA RATE curves	18
•	Changed RESIDUAL PEAK-TO-PEAK JITTER vs DATA RATE curves	18
•	Changed RESIDUAL PEAK-TO-PEAK JITTER vs DATA RATE curves	19
•	Added RESIDUAL PEAK-TO-PEAK JITTER vs DATA RATE curves	19

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



	*All	dimensions	are	nominal
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Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TMDS442PNPR	HTQFP	PNP	128	1000	330.0	24.4	16.6	16.6	2.0	20.0	24.0	Q2



PACKAGE MATERIALS INFORMATION

19-Mar-2008



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TMDS442PNPR	HTQFP	PNP	128	1000	346.0	346.0	41.0

PNP (S-PQFP-G128)

PowerPAD[™] PLASTIC QUAD FLATPACK



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion

This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com http://www.ti.com. See the product data sheet for details regarding the exposed thermal pad dimensions.

PowerPAD is a trademark of Texas Instruments.





THERMAL PAD MECHANICAL DATA

PNP (S-PQFP-G128)

THERMAL INFORMATION

This PowerPAD[™] package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

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